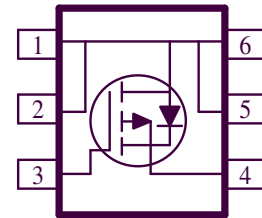
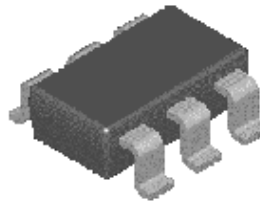


## P-Channel 100-V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low  $r_{DS(on)}$  and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

- Low  $r_{DS(on)}$  provides higher efficiency and extends battery life
- Low thermal impedance copper leadframe TSOP-6 saves board space
- Fast switching speed
- High performance trench technology



PRODUCT SUMMARY		
$V_{DS}$ (V)	$r_{DS(on)}$ ( $\Omega$ )	$I_D$ (A)
-100	0.350 @ $V_{GS} = -10V$	2.0
	0.450 @ $V_{GS} = -4.5V$	1.8

ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ UNLESS OTHERWISE NOTED)				
Parameter		Symbol	Maximum	Units
Drain-Source Voltage		$V_{DS}$	-100	V
Gate-Source Voltage		$V_{GS}$	$\pm 20$	
Continuous Drain Current <sup>a</sup>	$T_A = 25^\circ\text{C}$	$I_D$	2.0	A
	$T_A = 70^\circ\text{C}$		1.6	
Pulsed Drain Current <sup>b</sup>		$I_{DM}$	$\pm 8$	
Continuous Source Current (Diode Conduction) <sup>a</sup>		$I_S$	-2.1	A
Power Dissipation <sup>a</sup>	$T_A = 25^\circ\text{C}$	$P_D$	2.0	W
	$T_A = 70^\circ\text{C}$		1.3	
Operating Junction and Storage Temperature Range		$T_J, T_{stg}$	-55 to 150	$^\circ\text{C}$

THERMAL RESISTANCE RATINGS				
Parameter		Symbol	Maximum	Units
Maximum Junction-to-Ambient <sup>a</sup>	$t \leq 5$ sec	$R_{\theta JA}$	62.5	$^\circ\text{C}/\text{W}$
			110	$^\circ\text{C}/\text{W}$

### Notes

- Surface Mounted on 1" x 1" FR4 Board.
- Pulse width limited by maximum junction temperature

SPECIFICATIONS ( $T_A = 25^\circ\text{C}$ UNLESS OTHERWISE NOTED)						
Parameter	Symbol	Test Conditions	Limits			Unit
			Min	Typ	Max	
<b>Static</b>						
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = -250 \mu\text{A}$	-1			
Gate-Body Leakage	$I_{GSS}$	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			$\pm 100$	nA
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = -80 \text{ V}, V_{GS} = 0 \text{ V}$			-1	uA
		$V_{DS} = -80 \text{ V}, V_{GS} = 0 \text{ V}, T_J = 55^\circ\text{C}$			-10	
On-State Drain Current <sup>A</sup>	$I_{D(on)}$	$V_{DS} = -5 \text{ V}, V_{GS} = -10 \text{ V}$	-20			A
Drain-Source On-Resistance <sup>A</sup>	$r_{DS(on)}$	$V_{GS} = -10 \text{ V}, I_D = -1.4 \text{ A}$			350	m $\Omega$
		$V_{GS} = -4.5 \text{ V}, I_D = -1.2 \text{ A}$			450	
Forward Transconductance <sup>A</sup>	$g_{fs}$	$V_{DS} = -15 \text{ V}, I_D = -1.4 \text{ A}$		2.8		S
Diode Forward Voltage	$V_{SD}$	$I_S = -1.4 \text{ A}, V_{GS} = 0 \text{ V}$			-1	V
<b>Dynamic<sup>b</sup></b>						
Total Gate Charge	$Q_g$	$V_{DS} = -30 \text{ V}, V_{GS} = -4.5 \text{ V},$ $I_D = -1.4 \text{ A}$		6		nC
Gate-Source Charge	$Q_{gs}$			10		
Gate-Drain Charge	$Q_{gd}$			3		
Turn-On Delay Time	$t_{d(on)}$	$V_{DD} = -30 \text{ V}, R_L = 30 \Omega, I_D = -1 \text{ A},$ $V_{GEN} = -10 \text{ V}, R_G = 6\Omega$		3		nS
Rise Time	$t_r$			3		
Turn-Off Delay Time	$t_{d(off)}$			13		
Fall-Time	$t_f$			7		

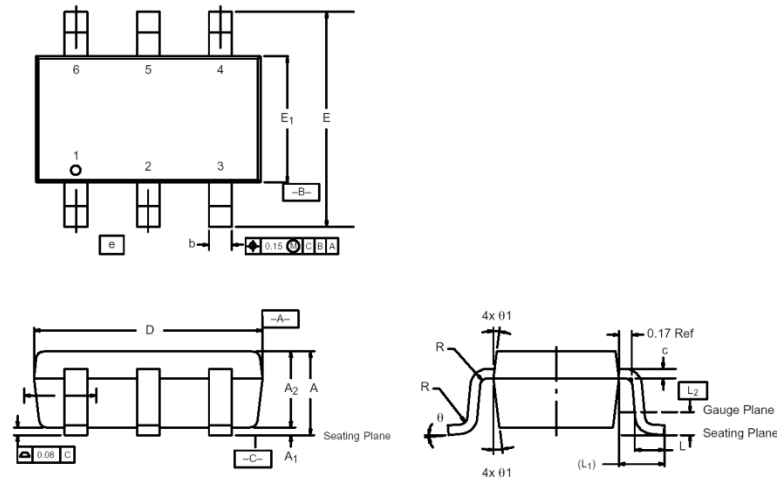
## Notes

- Pulse test:  $PW \leq 300\mu\text{s}$  duty cycle  $\leq 2\%$ .
- Guaranteed by design, not subject to production testing.

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Package Information

TSOP-6: 6LEAD



Dim	MILLIMETERS			INCHES		
	Min	Nom	Max	Min	Nom	Max
A	0.91	–	1.10	0.036	–	0.043
A <sub>1</sub>	0.01	–	0.10	0.0004	–	0.004
A <sub>2</sub>	0.84	–	1.00	0.033	0.038	0.039
b	0.30	0.32	0.45	0.012	0.013	0.018
c	0.10	0.15	0.20	0.004	0.006	0.008
D	2.95	3.05	3.10	0.116	0.120	0.122
E	2.70	2.85	2.98	0.106	0.112	0.117
E <sub>1</sub>	1.55	1.65	1.70	0.061	0.065	0.067
e	1.00 BSC			0.0394 BSC		
L	0.35	–	0.50	0.014	–	0.020
L <sub>1</sub>	0.60 Ref			0.024 Ref		
L <sub>2</sub>	0.25 BSC			0.010 BSC		
R	0.10	–	–	0.004	–	–
θ	0°	4°	8°	0°	4°	8°
θ <sub>1</sub>	7° Nom			7° Nom		